L Number	Hits	Search Text	DB	Time stamp
1	41267	"semiconductor memory" and "memory cell"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/07 16:35
2	97088	DRAM or (dynamic adj5 random adj5 access adj5 memory)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/07 16:04
3	13849	("semiconductor memory" and "memory cell") and (DRAM or (dynamic adj5 random adj5 access adj5 memory))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/07 16:04
4	6757	(("semiconductor memory" and "memory cell") and (DRAM or (dynamic adj5 random adj5 access adj5 memory))) and (sense adj3 amplifier)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/07 16:05
5	4822	((("semiconductor memory" and "memory cell") and (DRAM or (dynamic adj5 random adj5 access adj5 memory))) and (sense adj3 amplifier)) and row and column and array	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/07 16:05
6	4		USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/07
7	1828	(DRAM or (dynamic adj5 random adj5 access adj5 memory)) and PMOS and NMOS and "memory cell array"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/07 16:08
8	1259	((DRAM or (dynamic adj5 random adj5 access adj5 memory)) and PMOS and NMOS and "memory cell array") and transistor and well	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/07 16:09
9	21	(((DRAM or (dynamic adj5 random adj5 access adj5 memory)) and PMOS and NMOS and "memory cell array") and transistor and well) and sub\$ldecoder	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/07
10	790	(((("semiconductor memory" and "memory cell") and (DRAM or (dynamic adj5 random adj5 access adj5 memory))) and (sense adj3 amplifier)) and row and column and array) and (sub\$ldecoder or pre\$ldecoder)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/07
11	684	<pre>((((("semiconductor memory" and "memory cell") and (DRAM or (dynamic adj5 random adj5 access adj5 memory))) and (sense adj3 amplifier)) and row and column and array) and (sub\$ldecoder or pre\$ldecoder)) and 365/\$7.ccls.</pre>	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/07 16:33
14	79	<pre>((((("semiconductor memory" and "memory cell") and (DRAM or (dynamic adj5 random adj5 access adj5 memory))) and (sense adj3 amplifier)) and row and column and array) and (sub\$ldecoder or pre\$ldecoder)) and 365/63.ccls.</pre>	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/07 16:35
15	15711	"semiconductor memory" near5 "memory cell"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/07 16:35

16	819	("semiconductor memory" near5 "memory	USPAT;	2004/06/07
1	ļ	cell") near5 (DRAM or (dynamic adj5	US-PGPUB;	16:51
		random adj5 access adj5 memory))	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
18	23	(("semiconductor memory" near5 "memory	USPAT;	2004/06/07
		cell") near5 (DRAM or (dynamic adj5	US-PGPUB;	16:52
		random adj5 access adj5 memory))) near10	EPO; JPO;	
		amplifier	DERWENT;	
	}	ampilitel	IBM TDB	
10	22570	Umamanı gallu gama norr gama gallumn	USPAT;	2004/06/07
19	23578	"memory cell" same row same column		1 1
			US-PGPUB;	16:38
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	, ,
20	2366	("memory cell" same row same column) same	USPAT;	2004/06/07
		substrate	US-PGPUB;	16:39
Ì			EPO; JPO;	
			DERWENT;	
			IBM TDB	
22	67	(("memory cell" same row same column)	USPAT;	2004/06/07
1		same substrate) same amplifier same	US-PGPUB;	16:47
		"memory array"	EPO; JPO;	
		momory array	DERWENT;	
			IBM TDB	
22	2	(("memory cell" same row same column)	USPAT;	2004/06/07
23	2		1	16:55
		same substrate) same amplifier same	US-PGPUB;	10:22
		sub\$1decoder	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
24	450	"sense amplifier driver"	USPAT;	2004/06/07
			US-PGPUB;	16:53
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
28	9	"sense amplifier driver" and subdecoder	USPAT;	2004/06/07
	1		US-PGPUB;	16:57
			EPO; JPO;	
			DERWENT;	
+			IBM TDB	
29	15	subdecoder near5 amplifier	USPAT;	2004/06/07
29	13	Subdecoder Hears amprilier	US-PGPUB;	16:56
				16.36
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	0004/06/07
30	283	"sense amplifier driver" and decoder	USPAT;	2004/06/07
			US-PGPUB;	16:57
			EPO; JPO;	
			DERWENT;	
-			IBM_TDB	
31	53	,	USPAT;	2004/06/07
		and gap and row and column	US-PGPUB;	16:58
			EPO; JPO;	
1			DERWENT;	
-			IBM TDB	
32	53	(("sense amplifier driver" and decoder)	USPAT;	2004/06/07
		and gap and row and column) and memory	US-PGPUB;	16:58
		gop and att and obtained, and moniory	EPO; JPO;	
			DERWENT;	
			IBM TDB	
34	41	///!gongo amplifion duissau! and daged	USPAT;	2004/06/07
ا ا	41	((("sense amplifier driver" and decoder)		17:08
		and gap and row and column) and memory)	US-PGPUB;	17:00
		and 365/\$7	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
35	123	kawasaki-satoshi.in.	USPAT;	2004/06/07
			US-PGPUB;	17:08
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	

36	1	kawasaki-satoshi-\$.in.	USPAT;	2004/06/07
			US-PGPUB;	17:09
			EPO; JPO;	
i			DERWENT;	
			IBM TDB	